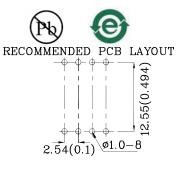
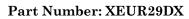


Features

- \bullet Robust package
- \bullet Uniform light disbursement
- Ideal for backlighting logos or icons
- Excellent for flush mounting
- RoHS compliant





15mmx15mm LIGHT BAR

Package Schematics □15(0.591) 8765 ORIENTATION MARK 12.55(0.494) .25(0.01) +0.25 5(0.098)ö Ni 1 2 3 4 0.8(0.031) $11.2(0.441) 4(0.157) \pm 0.5$.5(0.098) 2 3 6 7 ¥ ¥ Ŷ $+0.25 \\ -0.1$ Ni 0.5(0.02) 5 8 1 4 2.54(0.1)

Notes: 1. All dimensions are in millimeters (inches), Tolerance is ±0.25(0.01")unless otherwise noted. 2. Specifications are subject to change without notice.

Absolute Maximum Ratings (T _A =25°C)		UR (GaAsP/GaP)	Unit	
Reverse Voltage	V_{R}	5	V	
Forward Current	$I_{\rm F}$	30	mA	
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	ifs	160	mA	
Power Dissipation	P_{D}	75	mW	
Operating Temperature	$T_{\rm A}$	$-40 \sim +85$	°C	
Storage Temperature	Tstg	$-40 \sim +85$		
Lead Solder Temperature [2mm Below Package Base]	260°C For 3-5 Seconds			

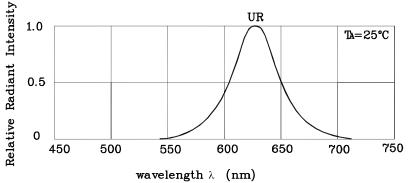
Operating Characteristics (T _A =25°C)		UR (GaAsP/GaP)	Unit
Forward Voltage (Typ.) (I _F =10mA)	V_{F}	1.9	V
Forward Voltage (Max.) (I _F =10mA)	V_{F}	2.5	V
Reverse Current (Max.) (V _R =5V)	I_{R}	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I _F =10mA)	λP	627*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) (I _F =10mA)	λD	617*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =10mA)	$ riangle\lambda$	45	nm
Capacitance (Typ.) (V _F =0V, f=1MHz)	С	15	$_{ m pF}$

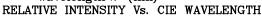
Part Number	Emitting Color	Emitting Material	Luminous Intensity CIE127-2007* (I _F =10mA) mcd		Wavelength CIE127-2007* nm λΡ	Lens-color
			min.	typ.		
XEUR29DX	Red	GaAsP/GaP	21 3.6*	32 8*	627*	Red Diffused

*Luminous intensity value and wavelength are in accordance with CIE127-2007 Mar 05,2014

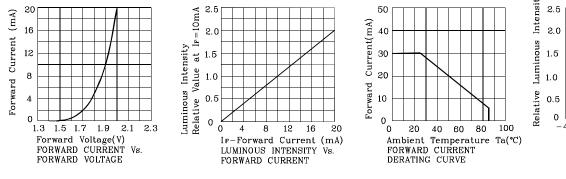
XDSA1963 V6-X Layout: Maggie L.

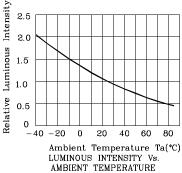




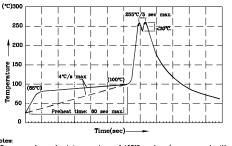


♦ UR





Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



Access I.Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C 2.Peak wave soldering temperature between 245°C ~ 255°C for 3 sec (5 sec max)

Peak wave soldering temperature between 2+30 - 2+30

Remarks:

If special sorting is required (e.g. binning based on forward voltage,

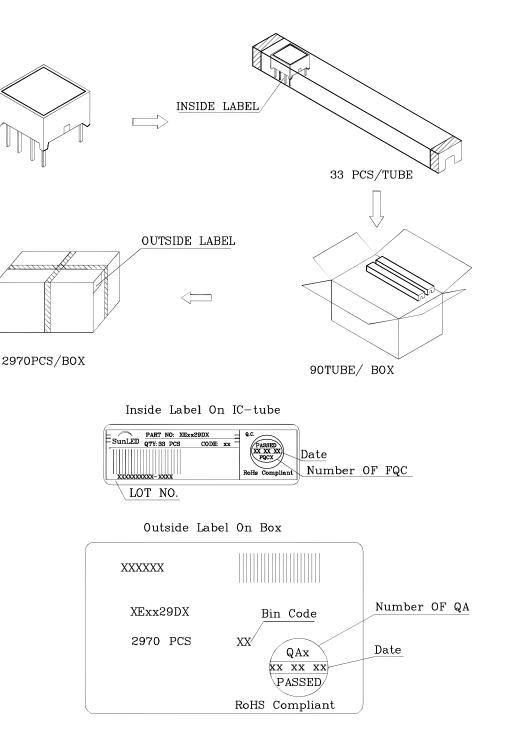
luminous intensity / luminous flux, or wavelength),

the typical accuracy of the sorting process is as follows:

- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V
- Note: Accuracy may depend on the sorting parameters.



PACKING & LABEL SPECIFICATIONS



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- 1. Data presented in this document reflect statistical figures and should be treated as technical reference only.
- 2. Contents within this document are subject to improvement and enhancement changes without notice.
- 3. The product(s) in this document are designed to be operated within the electrical and environmental specifications indicated on the datasheet.
- User accepts full risk and responsibility when operating the product(s) beyond their intended specifications.
- 4. The product(s) described in this document are intended for electronic applications in which a person's life is not reliant upon the LED. Please
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- 5. The contents within this document may not be altered without prior consent by SunLED.
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